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捷多邦,专业PCB打样工厂,24小时加急出货74AC11000 QUADRUPLE 2-INPUT POSITIVE-NAND GATE

SCLS054A - APRIL 1987 - REVISED APRIL 1996

 Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise 	D OR N PACKAGE (TOP VIEW)
 EPIC ™ (Enhanced-Performance Implanted CMOS) 1-μm Process 	
 500-mA Typical Latch-Up Immunity at 125°C 	1Y 2 15 2A 2Y 3 14 2B GND 4 13 V _{CC}
Package Options Include Plastic Small-Outline (D) Packages and Standard	GND [5 12] V _{CC} 3Y [6 11] 3A
Plastic 300-mil DIPs (N) description	4Y [7 10] 3B 4B [8 9] 4A

This device contains four independent 2-input NAND gates. It performs the Boolean function $Y = \overline{A \cdot B}$ or $Y = \overline{A + B}$ in positive logic.

The 74AC11000 is characterized for operation from -40°C to 85°C.

	FUNCTION TABLE (each gate)								
-	INP	UTS	OUTPUT						
100	А	В	Y						
	C H	Н	L						
	L	Х	Н						
	Х	L	Н						

logic symbol[†]

	1				
1 A	16	&		2	1Y
1A 1B 2A 2B 3A	15		122	2	
2R	14	0		3	2Y
24	11	A		~	
3R	10		<u> </u>	6	3Y
4.0	9			-	
3B 4A 4B	8		<u> </u>		4Y
			J		

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



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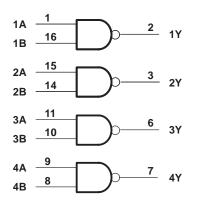
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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (see Note 1)	$\dots -0.5$ V to V _{CC} + 0.5 V
Output voltage range, V _O (see Note 1)	–0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I_{OK} (V _O < 0 or V _O > V _{CC})	±50 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 2): D package	1.3 W
N package	1.1 W
Storage temperature range, T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.



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			MIN	NOM	MAX	UNIT	
Vcc	Supply voltage		3	5	5.5	V	
		V _{CC} = 3 V	2.1				
VIH	High-level input voltage	$V_{CC} = 4.5 V$	3.15			V	
		V _{CC} = 5.5 V	3.85				
		V _{CC} = 3 V			0.9	.9	
VIL	Low-level input voltage	$V_{CC} = 4.5 V$			1.35	V	
		V _{CC} = 5.5 V			1.65		
VI	Input voltage	•			VCC	V	
Vo	Output voltage		0		VCC	V	
		V _{CC} = 3 V			-4		
IOH	High-level output current	$V_{CC} = 4.5 V$			-24	mA	
		V _{CC} = 5.5 V			-24		
		V _{CC} = 3 V			12		
IOL	Low-level output current	V _{CC} = 4.5 V			24	mA	
		V _{CC} = 5.5 V			24		
$\Delta t / \Delta v$	Input transition rise or fall rate	•	0		10	ns/V	
Τ _Α	Operating free-air temperature		-40		85	°C	

recommended operating conditions

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vee	Τ ₄	λ = 25°C		MIN	МАХ	UNIT
		Vcc	MIN	TYP	MAX	IVIIIN	IVIAA	UNIT
		3 V	2.9			2.9		
	I _{OH} = -50 μA	4.5 V	4.4			4.4		
		5.5 V	5.4			5.4		
VOH	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		V
		4.5 V	3.94			3.8		
	I _{OH} = -24 mA	5.5 V	4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V				3.85		
					0.1		0.1	
	I _{OL} = 50 μA	4.5 V			0.1		0.1	
		5.5 V			0.1		0.1	
VOL	I _{OL} = 12 mA	3 V			0.36		0.44	V
	I _{OL} = 24 mA	4.5 V			0.36		0.44]
		5.5 V			0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V					1.65	
lj	$V_I = V_{CC}$ or GND	5.5 V			±0.1		±1	μΑ
Icc	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V			0.4		40	μA
Ci	$V_I = V_{CC}$ or GND	5 V		3.5				pF

[†] Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.



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switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT) TA = 25°C MIN MAX	T _A = 25°C				UNIT	
PARAMETER			(OUTPUT)	IVIAA	UNIT			
^t PLH	A or B	V	1.5	7.2	9.8	1.5	11.1	
^t PHL	AUB	Ŷ	1.5	5.8	8.6	1.5	9.6	ns

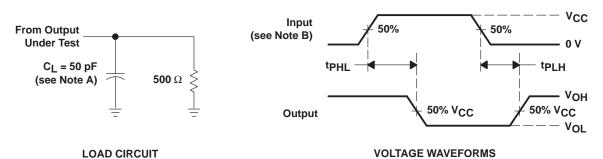
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM TO (INPUT) (OUTPUT	ТО	Т	_A = 25°C	;	MIN	MAX	UNIT
PARAMETER		(OUTPUT)	MIN	TYP	MAX	UNIT		
^t PLH	A or B	V	1.5	5	6.5	1.5	7.4	
^t PHL	AUID	T	1.5	4.4	6.1	1.5	6.8	ns

operating characteristics, $V_{CC} = 5 V$, $T_A = 25^{\circ}C$

	PARAMETER TEST CONDITIONS		TYP	UNIT	
C _{pd}	Power dissipation capacitance per gate	C _L = 50 pF,	f = 1 MHz	33	pF

PARAMETER MEASUREMENT INFORMATION



NOTES: A. CL includes probe and jig capacitance.

B. Input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_f = 3 ns, t_f = 3 ns.

C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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